

# BGU7051

## SiGe:C low noise high linearity amplifier

Rev. 2 — 11 November 2011

Product data sheet

## 1. Product profile

### 1.1 General description

The BGU7051 is a low noise high linearity amplifier for wireless infrastructure applications. The LNA has a high input and output return loss and is designed to operate between 0.5 GHz and 1.5 GHz. It is housed in a  $3 \times 3 \times 0.85 \text{ mm}^3$  10-terminal plastic thin small outline package. The LNA is ESD protected on all terminals.

### 1.2 Features and benefits

- Low Noise Figure (NF) = 0.65 dB at 900 MHz
- High linearity performance,  $IP3O = 33 \text{ dBm}$  at 900 MHz
- High input and output return loss
- Unconditionally stable
- 110 GHz transit frequency - SiGe:C technology
- Supply voltage 3.3 V
- Small 10-terminal leadless package  $3 \times 3 \times 0.85 \text{ mm}^3$
- ESD protection on all terminals
- Moisture sensitivity level 1

### 1.3 Applications

- LNA for wireless infrastructure applications (0.5 GHz to 1.5 GHz)
- Low noise applications

### 1.4 Quick reference data

**Table 1. Quick reference data**

*f = 900 MHz; V<sub>CC</sub> = 3.3 V; T<sub>amb</sub> = 25 °C; input and output 50 Ω; unless otherwise specified.*

| Symbol              | Parameter                             | Conditions | Min  | Typ  | Max  | Unit |
|---------------------|---------------------------------------|------------|------|------|------|------|
| V <sub>CC</sub>     | supply voltage                        |            | 3.0  | -    | 3.6  | V    |
| I <sub>CC</sub>     | supply current                        |            | 50   | 65   | 80   | mA   |
| G <sub>ass</sub>    | associated gain                       |            | 19.5 | 21.0 | 22.5 | dB   |
| NF                  | noise figure                          |            | -    | 0.65 | 0.95 | dB   |
| P <sub>L(1dB)</sub> | output power at 1 dB gain compression |            | 15   | 16.5 | -    | dBm  |
| IP <sub>3O</sub>    | output third-order intercept point    |            | 30   | 33   | -    | dBm  |



## 2. Pinning information

### 2.1 Pinning

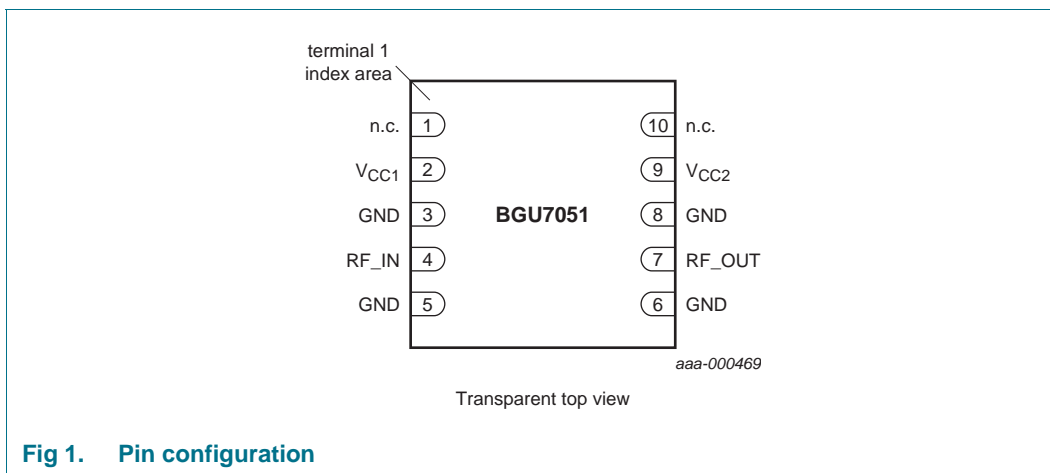


Fig 1. Pin configuration

### 2.2 Pin description

Table 2. Pin description

| Symbol           | Pin        | Description    |
|------------------|------------|----------------|
| n.c.             | 1, 10      | not connected  |
| V <sub>CC1</sub> | 2          | supply voltage |
| GND              | 3, 5, 6, 8 | ground         |
| RF_IN            | 4          | RF input       |
| RF_OUT           | 7          | RF output      |
| V <sub>CC2</sub> | 9          | supply voltage |

## 3. Ordering information

Table 3. Ordering information

| Type number | Package |  |          |
|-------------|---------|--|----------|
|             | Name    | Description  | Version  |
| BGU7051     | HVSON10 | plastic thermal enhanced very thin small outline package; no leads; 10 terminals; body 3 × 3 × 0.85 mm | SOT650-1 |

## 4. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol        | Parameter                          | Conditions   | Min | Max | Unit |
|---------------|------------------------------------|--|-----|-----|------|
| $V_{CC}$      | supply voltage                     |  | 0   | 5   | V    |
| $P_{i(RF)CW}$ | continuous waveform RF input power | $V_{CC} = 3.3$ V   | -   | 20  | dBm  |
| $T_{stg}$     | storage temperature                |  | -65 | 150 | °C   |
| $T_j$         | junction temperature               |  | -   | 150 | °C   |
| $T_{amb}$     | ambient temperature                |  | -40 | 85  | °C   |
| $V_{ESD}$     | electrostatic discharge voltage    | Human Body Model (HBM);<br>According JEDEC standard 22-A114E     | -   | 4   | kV   |
|               |                                    | Charged Device Model (CDM);<br>According JEDEC standard 22-C101B | -   | 2   | kV   |

## 5. Thermal characteristics

**Table 5. Thermal characteristics**

| Symbol         | Parameter  | Conditions | Typ | Unit |
|----------------|--|------------|-----|------|
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point |            | 26  | K/W  |

## 6. Characteristics

**Table 6. Characteristics**

$V_{CC} = 3.3$  V;  $T_{amb} = 25$  °C; input and output 50  $\Omega$ ; unless otherwise specified. All RF parameters are measured at the device RF in and RF output terminals.

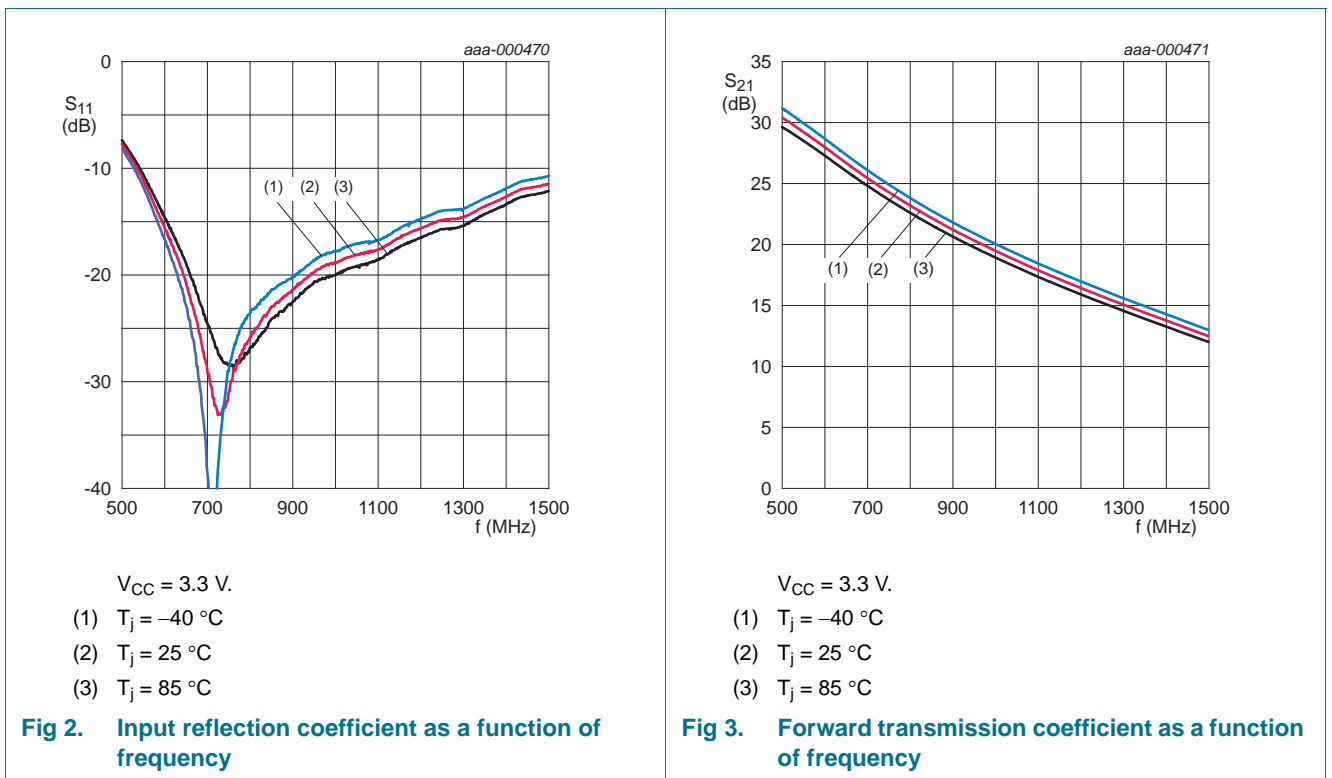
| Symbol           | Parameter                             | Conditions                             | Min  | Typ  | Max  | Unit |
|------------------|---------------------------------------|--|------|------|------|------|
| $V_{CC}$         | supply voltage                        |  | 3.0  | -    | 3.6  | V    |
| $I_{CC}$         | supply current                        |  | 50   | 65   | 80   | mA   |
| $G_{ass}$        | associated gain                       | f = 750 MHz                            | -    | 23.5 | -    | dB   |
|                  |                                       | f = 850 MHz                            | -    | 21.5 | -    | dB   |
|                  |                                       | f = 900 MHz                            | 19.5 | 21.0 | 22.5 | dB   |
| NF               | noise figure                          | f = 750 MHz                            | -    | 0.6  | -    | dB   |
|                  |                                       | f = 850 MHz                            | -    | 0.63 | -    | dB   |
|                  |                                       | f = 900 MHz                            | -    | 0.65 | 0.95 | dB   |
| $P_{L(1dB)}$     | output power at 1 dB gain compression | f = 750 MHz                            | -    | 17.0 | -    | dBm  |
|                  |                                       | f = 850 MHz                            | -    | 16.5 | -    | dBm  |
|                  |                                       | f = 900 MHz                            | 15   | 16.5 | -    | dBm  |
| IP3 <sub>O</sub> | output third-order intercept point    | 2-tone; spacing 5 MHz; $P_1 = -20$ dBm |      |      |      |      |
|                  |                                       | f = 750 MHz                            | -    | 32   | -    | dBm  |
|                  |                                       | f = 850 MHz                            | -    | 32   | -    | dBm  |
|                  |                                       | f = 900 MHz                            | 30   | 33   | -    | dBm  |

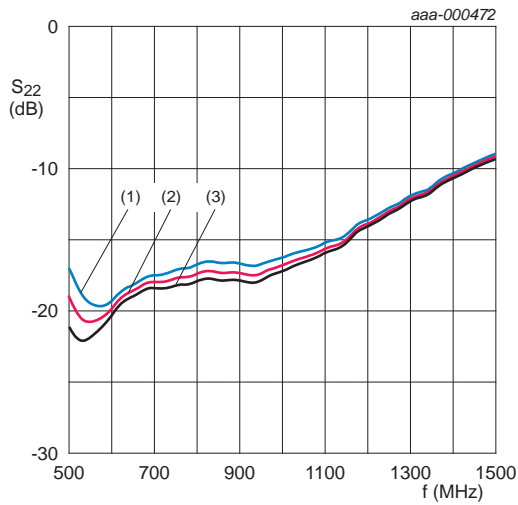
**Table 6. Characteristics ...continued**

$V_{CC} = 3.3\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ ; input and output  $50\ \Omega$ ; unless otherwise specified. All RF parameters are measured at the device RF in and RF output terminals.

| Symbol            | Parameter                | Conditions         | Min | Typ  | Max | Unit |
|-------------------|--------------------------|--------------------|-----|------|-----|------|
| RL <sub>in</sub>  | input return loss        | f = 750 MHz        | -   | 27.5 | -   | dB   |
|                   |                          | f = 850 MHz        | -   | 26.0 | -   | dB   |
|                   |                          | f = 900 MHz        | -   | 24.5 | -   | dB   |
| RL <sub>out</sub> | output return loss       | f = 750 MHz        | -   | 18.0 | -   | dB   |
|                   |                          | f = 850 MHz        | -   | 17.5 | -   | dB   |
|                   |                          | f = 900 MHz        | -   | 18   | -   | dB   |
| ISL               | isolation                | f = 750 MHz        | -   | 29.5 | -   | dB   |
|                   |                          | f = 850 MHz        | -   | 27.5 | -   | dB   |
|                   |                          | f = 900 MHz        | -   | 26.5 | -   | dB   |
| K                 | Rollett stability factor | 0 GHz ≤ f ≤ 25 GHz | 1   | -    | -   |      |

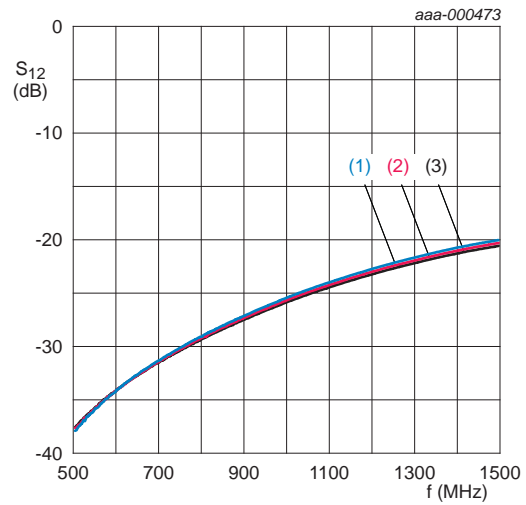
**6.1 Performance curves**





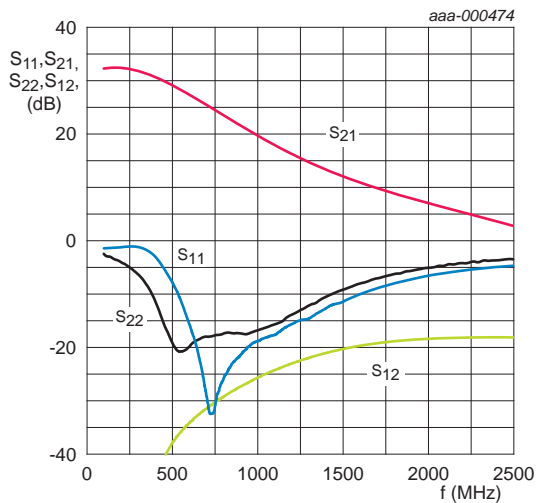
$V_{CC} = 3.3 \text{ V}$ .  
 (1)  $T_j = -40 \text{ }^\circ\text{C}$   
 (2)  $T_j = 25 \text{ }^\circ\text{C}$   
 (3)  $T_j = 85 \text{ }^\circ\text{C}$

**Fig 4. Output reflection coefficient as a function of frequency**



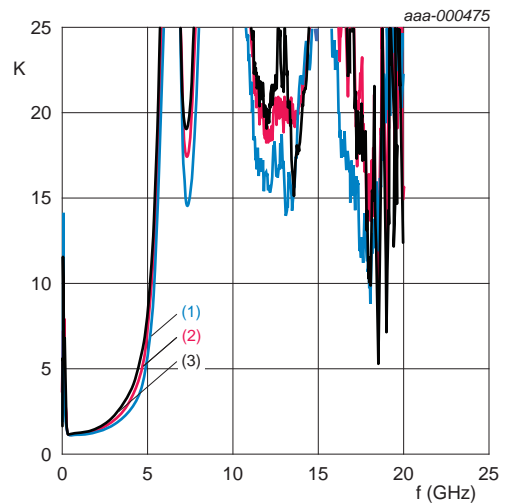
$V_{CC} = 3.3 \text{ V}$ .  
 (1)  $T_j = -40 \text{ }^\circ\text{C}$   
 (2)  $T_j = 25 \text{ }^\circ\text{C}$   
 (3)  $T_j = 85 \text{ }^\circ\text{C}$

**Fig 5. Reverse transmission coefficient as a function of frequency**



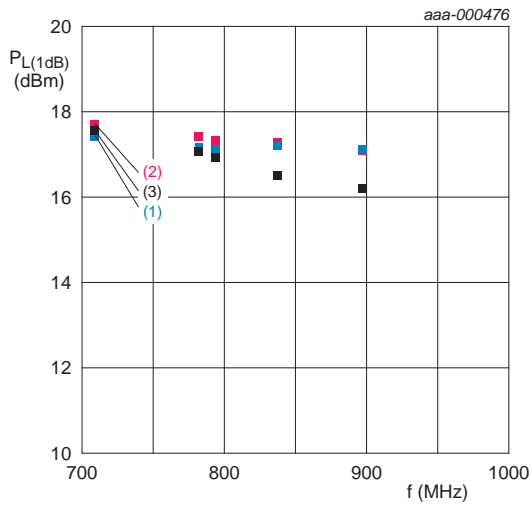
$V_{CC} = 3.3 \text{ V}; T_{amb} = 25 \text{ }^\circ\text{C}$ .

**Fig 6. Wideband s-parameters as a function of frequency**



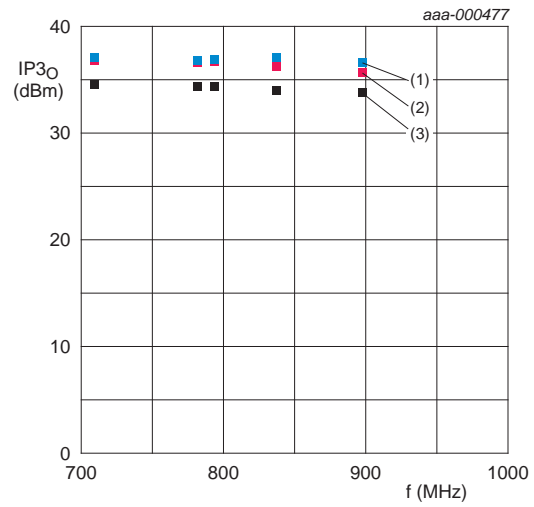
$V_{CC} = 3.3 \text{ V}$ .  
 (1)  $T_j = -40 \text{ }^\circ\text{C}$   
 (2)  $T_j = 25 \text{ }^\circ\text{C}$   
 (3)  $T_j = 85 \text{ }^\circ\text{C}$

**Fig 7. Stability K-factor as a function of frequency**



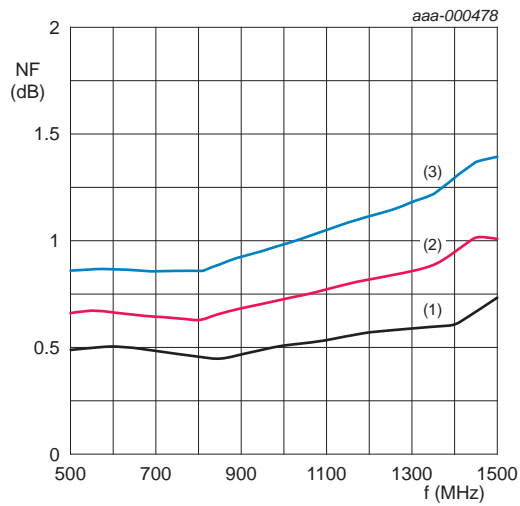
$V_{CC} = 3.3\text{ V}$ .  
 (1)  $T_j = -40^\circ\text{C}$   
 (2)  $T_j = 25^\circ\text{C}$   
 (3)  $T_j = 85^\circ\text{C}$

Fig. 8. Output power at 1 dB gain compression as a function of frequency



$V_{CC} = 3.3\text{ V}$ .  
 (1)  $T_j = -40^\circ\text{C}$   
 (2)  $T_j = 25^\circ\text{C}$   
 (3)  $T_j = 85^\circ\text{C}$

Fig. 9. Output third-order intercept point as a function of frequency



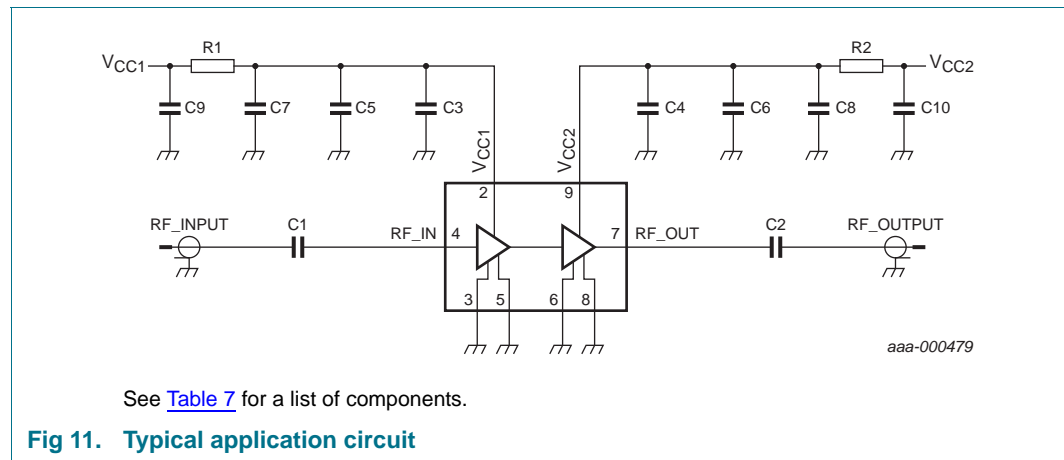
$V_{CC} = 3.3\text{ V}$ .  
 (1)  $T_j = -40^\circ\text{C}$   
 (2)  $T_j = 25^\circ\text{C}$   
 (3)  $T_j = 85^\circ\text{C}$

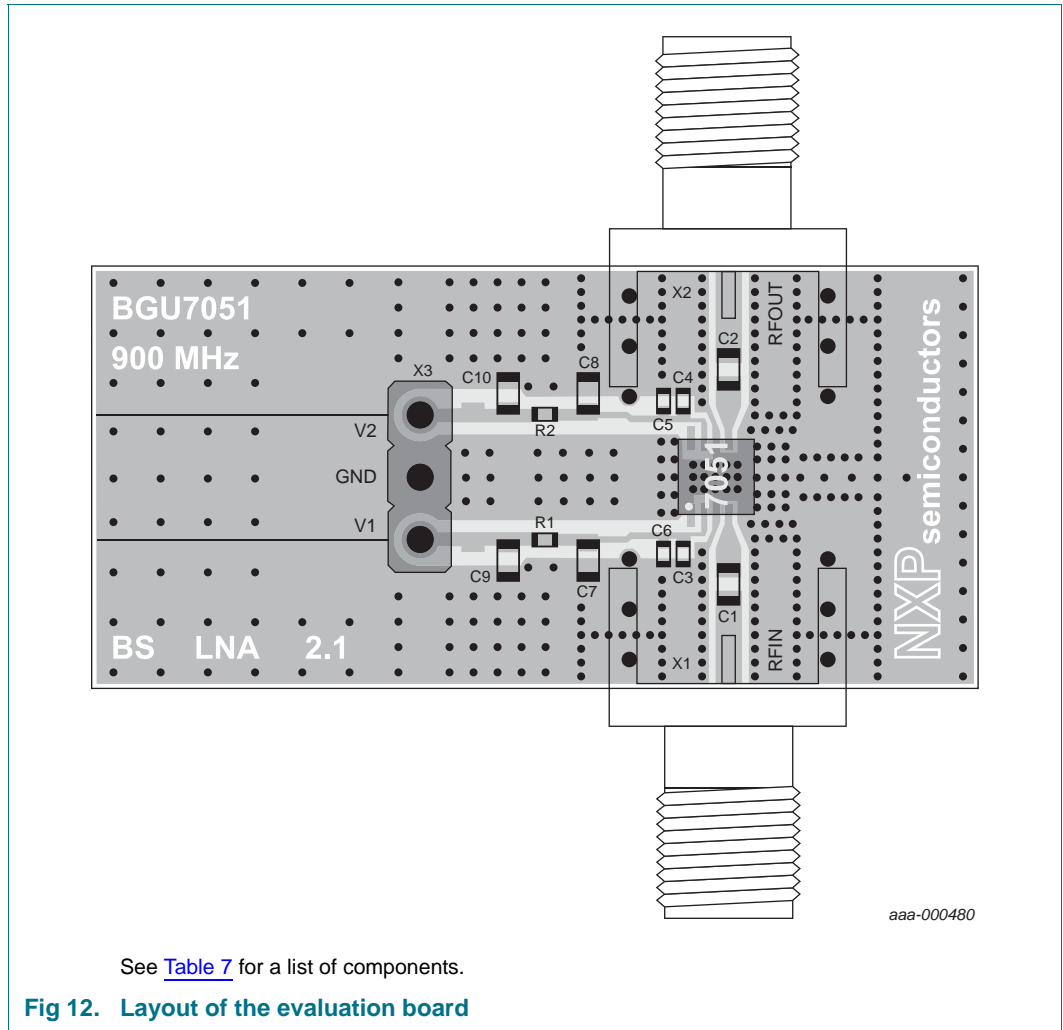
Fig. 10. Noise figure as function of frequency

## 7. Application information

[Figure 11](#) shows the typical application circuit for the BGU7051. The device is internally matched to 50 Ω, and therefore does not need any external matching. The value of the input and output DC blocking C1 and C2 are recommended to be 1 nF. DC decoupling capacitors C3 and C4 should be located as close as possible to the BGU7051.

In case different system blocks are supplied via the same voltage rail, it is recommended to use a bias choke in the bias line on the positions of R1 and R2. The value of this choke is depending on the frequency that needs to be decoupled.





**Table 7. List of components**

See [Figure 11](#) for schematics.

| Component       | Description | Value      | Size | Function        |
|-----------------|-------------|------------|------|-----------------|
| C1, C2          | capacitor   | [1] 1 nF   | 0402 | DC block        |
| C3, C4          | capacitor   | [1] 100 pF | 0402 | bias decoupling |
| C5, C6          | capacitor   | [1] 100 nF | 0402 | bias decoupling |
| C7, C8, C9, C10 | capacitor   | [2] 100 nF | 0603 | optional        |
| R1, R2          | resistor    | 0 Ω        | 0402 |                 |

[1] Murata GRM155 or capacitor of same quality.

[2] Murata GRM188 or capacitor of same quality.



## 8. Package outline

HVSON10: plastic thermal enhanced very thin small outline package; no leads;  
10 terminals; body 3 x 3 x 0.85 mm

SOT650-1

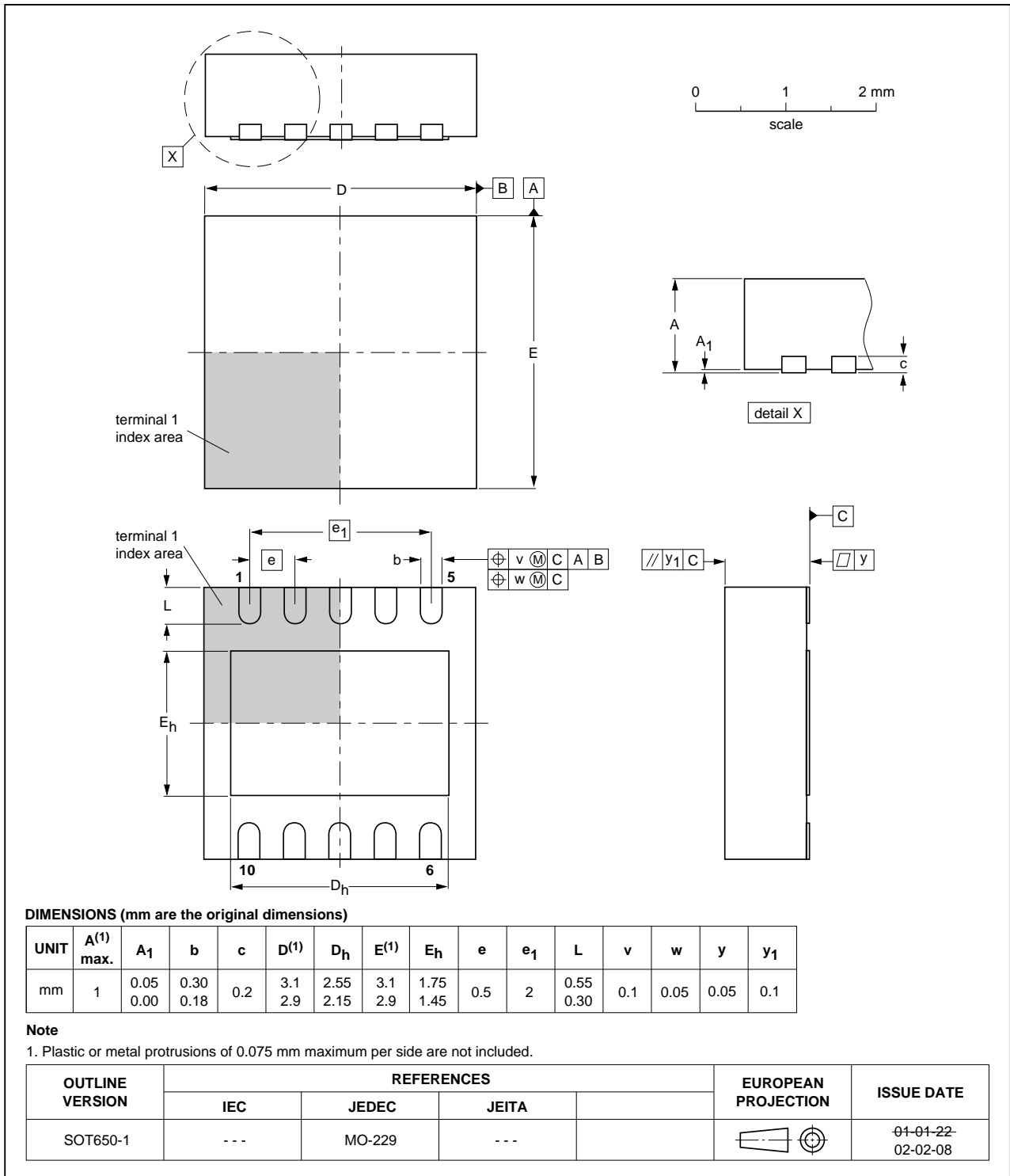


Fig 13. Package outline SOT650-1 (HVSON10)

## 9. Abbreviations

**Table 8. Abbreviations**

| Acronym | Description                  |
|---------|------------------------------|
| AC      | Alternating Current          |
| CW      | Continuous Wave              |
| ESD     | ElectroStatic Discharge      |
| ESR     | Equivalent Series Resistance |
| HBM     | Human Body Model             |
| LNA     | Low Noise Amplifier          |
| PDA     | Personal Digital Assistant   |
| RF      | Radio Frequency              |
| SiGe:C  | Silicon Germanium Carbon     |

## 10. Revision history

**Table 9. Revision history**

| Document ID    | Release date   | Data sheet status  | Change notice | Supersedes  |
|----------------|--|--------------------|---------------|-------------|
| BGU7051 v.2    | 20111111   | Product data sheet | -             | BGU7051 v.1 |
| Modifications: | <ul style="list-style-type: none"> <li>• <a href="#">Figure 10</a>: data plots updated</li> <li>• Unit dB changed to dBm for <math>P_{L(1dB)}</math> in <a href="#">Section 6 "Characteristics"</a></li> </ul> |                    |               |             |
| BGU7051 v.1    | 20111027   | Product data sheet | -             | -           |

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### 11.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

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[2] The term 'short data sheet' is explained in section "Definitions".

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